

IRFB38N20DPBF

Data Sheet

TO-220AB, MOSFET, N, 200V, 44A

Manufacturers <u>Infineon Technologies Corporation</u>

Package/Case TO-220AB

Product Type Transistors

RoHS Green

Lifecycle



Images are for reference only

Please submit RFQ for IRFB38N20DPBF or Email to us: sales@ovaga.com We will contact you in 12 hours.

RFO

General Description

Applications

• High frequency DC-DC converters

Benefits

- Low Gate-to-Drain Charge to Reduce Switching Losses
- Fully Characterized Capacitance Including Effective COSS to Simplify Design, (See App. Note AN1001)
- Fully Characterized Avalanche Voltage and Current

Features

Planar cell structure for wide SOA

Optimized for broadest availability from distribution partners

Product qualification according to JEDEC standard

Silicon optimized for applications switching below <100kHz

Industry standard through-hole power package

High-current carrying capability package (up to 195 A, die-size dependent)

Capable of being wave-soldered



Related Products



IRLTS6342TRPBF

Infineon Technologies Corporation TSOP-6



IRF9310PBF

Infineon Technologies Corporation SOIC-8



IRF9358TRPBF

Infineon Technologies Corporation SOP-8



IRFB3307ZPBF

Infineon Technologies Corporation TO-220AB



IRLHS6376TRPBF

Infineon Technologies Corporation PQFN2x2DD



IRFH9310TRPBF

Infineon Technologies Corporation PQFN-8



IRFB7430PBF

Infineon Technologies Corporation TO-220



IRF7351TRPBF

Infineon Technologies Corporation SOIC-8